

Diode Current Equation \rightarrow

The relationship between applied voltage V and the diode current I is exponential and is mathematically given by the equation called diode current equation. It is expressed as,

$$I = I_0 [e^{V/\eta V_T} - 1] \text{ A}$$

Where,

I_0 = Reverse saturation current in A

V = Applied Voltage

V_T = Volt equivalent of temperature in volts

$\eta = 1$ for Ge

$= 2$ for Si

The voltage equivalent of temperature (V_T) indicates dependence of diode current on temperature.

V_T for a given diode at temperature T is calculated as,

$$V_T = kT \text{ Volts}$$

$$\text{or } V_T = \frac{T}{11600}$$

Where,

k = Boltzmann's Constant $= 8.62 \times 10^{-5} \text{ eV/K}$
and T = Temperature in $^{\circ}\text{K}$

Thus at room temperature of 27°C

i.e. $T = (27 + 273)^{\circ}\text{K} = 300^{\circ}\text{K} =$

$$V_T = 8.62 \times 10^{-5} \times 300 = 0.02586 \text{ V}$$

$$\Rightarrow \boxed{V_T = 0.02586 \text{ V} \approx 26 \text{ mV}}$$

Note:

The diode current equation is applicable for all the conditions of diode i.e. unbiased, forward biased and reverse biased.

Q. A Ge diode is used in a rectifier circuit and is operating at a temperature of 25°C with a reverse saturation current of $1000 \mu\text{A}$. Calculate the value of forward current if it is forward biased by 0.22 V .

Soln - Given -

$$I_0 = 1000 \mu\text{A} = 1000 \times 10^{-6} \text{ A}$$

$$V = 0.22 \text{ V}$$

$$T = 25^{\circ}\text{C} = 25 + 273 = 298^{\circ}\text{K}$$

$$\therefore V_T = \frac{kT}{q} = \frac{8.62 \times 10^{-5} \times 298}{1} = 0.025 \text{ V}$$

and $\eta = 1$ for Ge

So, diode current equation,

$$I = I_0 [e^{V/\eta V_T} - 1]$$

$$= 1000 \times 10^{-6} [e^{0.22/1 \times 0.025} - 1]$$

$$= 1000 \times 10^{-6} \times 6633.24$$

$$= 6.6332 \text{ A}$$

Q. A Ge diode has a reverse saturation current of $3 \mu A$. Calculate the voltage at which 1% of the rated current will flow through the diode, at room temperature if diode is rated for 1 A.

Solⁿ- Here,

$$\eta = 1 \text{ for Ge}$$

$$I_0 = 3 \mu A = 3 \times 10^{-6} A$$

Rated current is 1 A, and

$$I = 1\% \text{ of rated current} = 0.01 A$$

$$V_T = 0.02586 V \text{ at room temperature}$$

Using diode current equation,

$$I = I_0 [e^{V/\eta V_T} - 1]$$

$$\therefore 0.01 = 3 \times 10^{-6} [e^{V/1 \times 0.02586} - 1]$$

$$\Rightarrow e^{V/0.02586} - 1 = \frac{0.01}{3 \times 10^{-6}} = \frac{10^4}{3}$$

$$\Rightarrow e^{V/0.02586} - 1 = 3333.33$$

$$\Rightarrow e^{V/0.02586} = 3334.34$$

$$\Rightarrow \frac{V}{0.02586} = \ln 3334.34 = 8.112$$

$$\Rightarrow V = \underline{0.2097 V} \text{ Ans.}$$